## NSN 5961-00-269-1833

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Inclosure Material:
Metal
Overall Length:
0.260 inches
Terminal Length:
1.020 inches
Overall Diameter:
0.366 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.210 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakover voltage, dc
Current Rating Per Characteristic:
2.50 amperes source cutoff current
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
80131-release6208 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0